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M62333P/FP, M62338P/FP

8-bit 3ch I²C BUS D/A Converter with Buffer Amplifiers

REJ03D0865-0400 Rev.4.00 Mar 25, 2008

Description

The M62333/M62338 is an integrated circuit semiconductor of CMOS structure with 3 channels of built in D/A converters with output buffer operational amplifiers.

The input is 2-wires serial method is used for the transfer format of digital data to allow connection with a microcomputer with minimum wiring.

The output buffer operational amplifier employs AB class output circuit with sync and source drive capacity of 1.0 mA or more, and it operates in the whole voltage range from V_{CC} to ground.

The M62333 and the M62338 differ only in their slave address.

Features

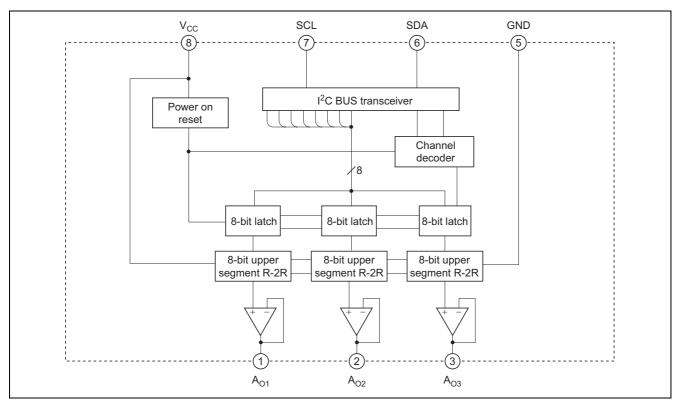
- Digital data transfer format: I²C BUS serial data method
- Output buffer operational amplifier: It operates in the whole voltage range from V_{CC} to ground.
- High output current drive capacity: ±1.0 mA over

Application

Conversion from digital data to analog control data for home-use and industrial equipment.

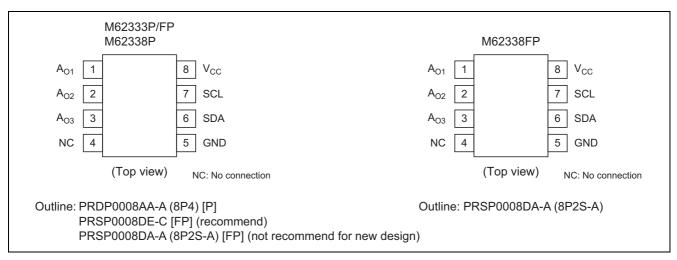
Signal gain control or automatic adjustment of Display-monitor or CTV.

Block Diagram



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Pin Arrangement



Pin Description

Pin No.	Pin Name	Function						
6	SDA	Serial data input terminal						
7	SCL	rial clock input terminal						
1	A _{O1}	8-bit resolution D/A converter output terminal						
2	A _{O2}							
3	A _{O3}							
8	V _{CC}	Power supply terminal						
5	GND	GND terminal						

Absolute Maximum Ratings

ltem	Symbol	Ratings	Unit
Supply voltage	V _{CC}	–0.3 to 7.0	V
Input voltage	Vin	–0.3 to V _{CC} + 0.3	V
Output voltage	Vo	–0.3 to V _{CC} + 0.3	V
Power dissipation	Pd	417 (P) / 272 (FP)	mW
Operating temperature	Topr	-20 to 85	°C
Storage temperature	Tstg	-40 to 125	°C

Electrical Characteristics

(V_{CC} = +5 V \pm 10%, GND = 0 V, Ta = -20 to 85°C unless otherwise noted)

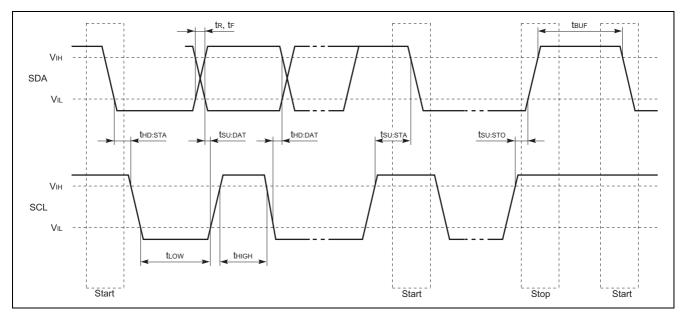
			Limits					
Item Symbol		Min	Тур	Max	Unit	Test Conditions		
Supply voltage	V _{CC}	2.7	5.0	5.5	V			
Supply current	I _{CC}	0	0.9	2.7	mA	CLK = 500 kHz operation, $I_{AO} = 0 \mu A$ Data: 6Ah (at maximum current)		
		0	0.6	1.8	mA	$SDA = SCL = GND, I_{AO} = 0 \mu A$		
Output low voltage (SDA)	V _{OL}	—	-	0.4	V	lsink = 3 mA		
Input leak current	I _{ILK}	-10	_	10	μΑ	$V_{IN} = 0$ to V_{CC}		
Input low voltage	VIL	—		0.2 V _{CC}	V			
Input high voltage	VIH	0.8 V _{CC}		—	V			
Buffer amplifier output	V _{AO}	0.1		$V_{CC} - 0.1$	V	$I_{AO} = \pm 100 \ \mu A$		
voltage range		0.2		$V_{CC}-0.2$	V	$I_{AO} = \pm 500 \ \mu A$		
Buffer amplifier output drive range	I _{AO}	-1.0	_	1.0	mA	Upper side saturation voltage = 0.3 V Lower side saturation voltage = 0.2 V		
Differential nonlinearity	S _{DL}	-1.0	_	1.0	LSB	V _{CC} = 5.12 V (20 mV/LSB)		
Nonlinearity	SL	-1.5		1.5	LSB	without load $(I_{AO} = 0)$		
Zero code error	SZERO	-2.0	_	2.0	LSB			
Full scale error	S _{FULL}	-2.0		2.0	LSB			
Output capacitate load	Co	_	_	0.1	μF			
Buffer amplifier output impedance	Ro		5.0	_	Ω			

I²C BUS Line Characteristics

Item	Symbol	Min	Max	Unit
SCL clock frequency	t _{SCL}	0	100	kHz
Time the bus must be free before a new transmission can start	t _{BUF}	4.7	—	μS
Hold time START condition	t _{HD:STA}	4.0	—	μS
(After this period, the first clock pulse is generated)				
Low period of the clock	t _{LOW}	4.7	—	μS
High period of the clock	t _{HIGH}	4.0	—	μS
Set-up time for START condition	t _{SU:STA}	4.7	—	μS
(Only relevant for a repeated START condition)				
Hold time DATA	t _{HD:DAT}	0	—	μS
Set-up time DATA	t _{SU:DAT}	250	—	ns
Rise time of both SDA and SCL lines	t _R	_	1000	ns
Fall time of both SDA and SCL lines	t _F	_	300	ns
Set-up time for STOP condition	t _{SU:STO}	4.0	—	μS

Note: Transmitter must internally provide at least a hold time to bridge the undefined region (300 ns Max) of the falling edge of SCL.

Timing Chart



I²C BUS Format

STA	Slave address	W	А	Sub address	Α	DAC data	Α	STP
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Note: STA: start condition, A: affirmation bit, W: write (SDA = Low), STP: stop condition

• Slave address



1

1

0

1

• Sub address

First -							➤ Last
х	x x x x			х	х	S1	S0
-		Don	't care				nnel t data

Channel select data **S**1 **S**0 **Channel Selection** 0 0 ch1 selection 0 1 ch2 selection

ch3 selection

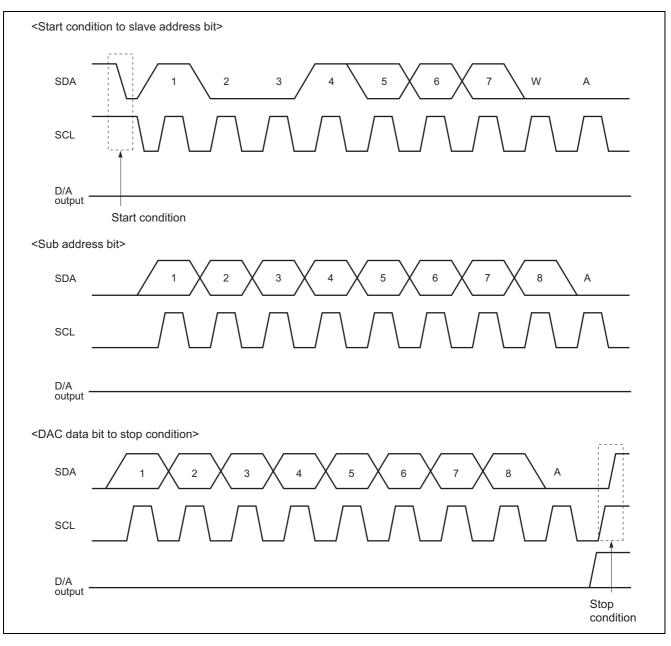
Don't care

0

• DAC data

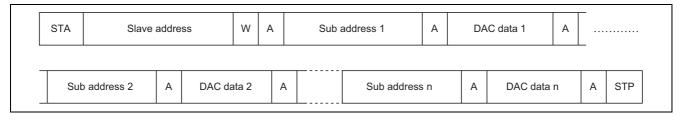
First MSB										
D7	D6	D5	D4	D3	D2	D1	D0			
First MSB	Last LSB									
D7	D6	D5	D4	D3	D2	D1		D0	DAC output	
0	0	0	0	0	0	0		0	V _{CC} / 256 × 1	
0	0	0	0	0	0	0		1	V_{CC} / 256 $ imes$ 2	
0	0	0	0	0	0	1		0	V_{CC} / 256 $ imes$ 3	
0	0	0	0	0	0	1		1	V_{CC} / 256 $\times4$	
:	:	:	:	:	:	:		:	:	
1	1	1	1	1	1	1		0	V_{CC} / 256 \times 255	
1	1	1	1	1	1	1		1	V _{CC}	

Timing Chart (Model)



- Start condition With SCL at High, SDA line goes from High to Low
- Stop condition With SCL at High, SDA line goes from Low to High
- (Under normal circumstances, SDA is changed when SCL is Low)
- Acknowledge bit The receiving IC has to pull down SDA line whenever receive slave data. (The transmitting IC releases the SDA line just then transmit 8-bit data.)

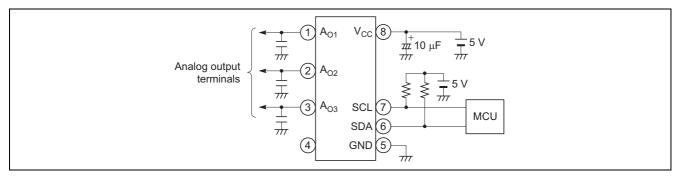
Digital Data Formats



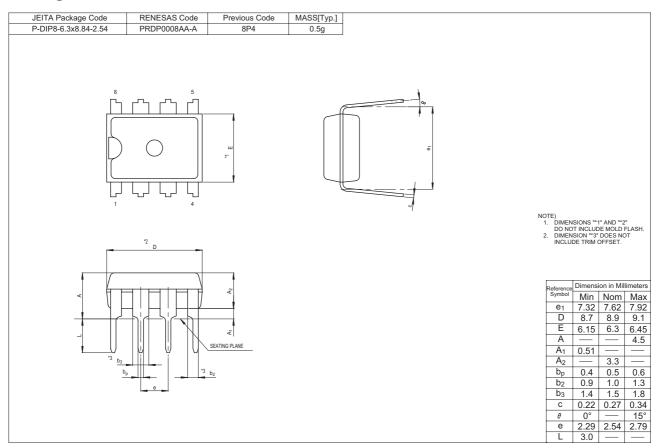
Precaution for Use

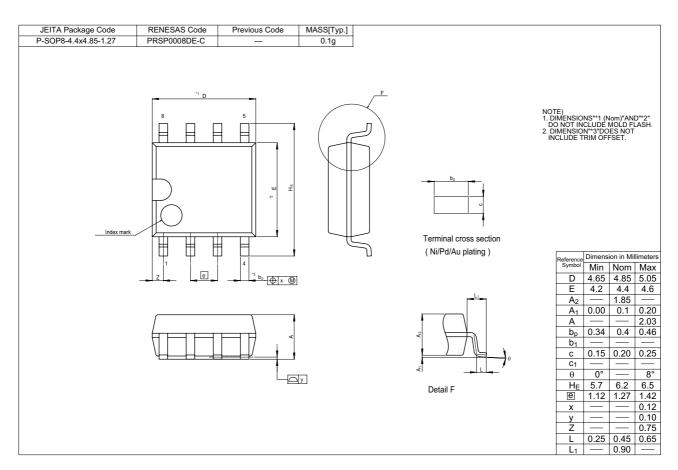
- Supply voltage terminal (V_{CC}) is also used for D/A converter upper reference voltage setting. If ripple or spike is input this terminal, accuracy of D/A conversion is down. So, when use this device, please connect capacitor among V_{CC} to GND for stable D/A conversion.
- This IC's output amplifier has an advantage to capacitive load. So it's no problem at device action when connect capacitor (0.1 μ F Max) among output to GND for every noise eliminate.
- Purchase of Renesas's I²C components conveys a license under the Philips I²C Patent Rights to use these components an I²C system, provided that the system conforms to I²C Standard Specification as defined by Philips.

Application Example



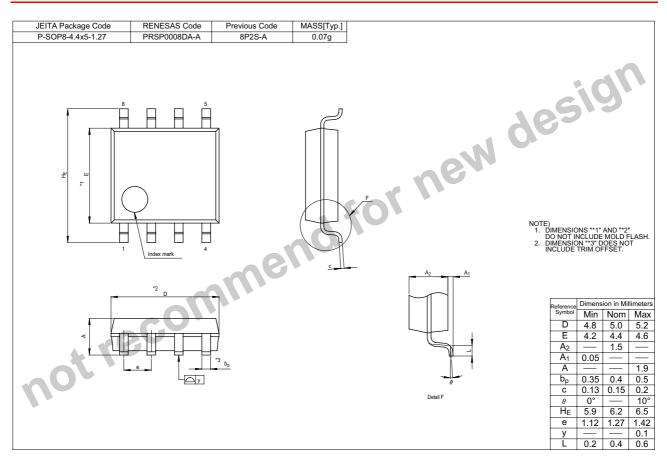
Package Dimensions





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M62333P/FP, M62338P/FP



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